

2KBP005M - 2KBP10M

2.0A GLASS PASSIVATED BRIDGE RECTIFIER

Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability
- Ideal for Printed Circuit Boards

Mechanical Data

Case: Molded Plastic

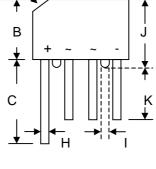
Terminals: Plated Leads Solderable per

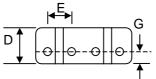
MIL-STD-202, Method 208

Polarity: As Marked on Body

Weight: 1.7 grams (approx.)Mounting Position: Any

Marking: Type Number





KBP						
Dim	Min	Max				
Α	14.22	15.24				
В	10.67	11.68				
С	15.2	_				
D	4.57	5.08				
E	3.60	4.10				
G	2.16	2.67				
H	0.76	0.86				
I	1.52	_				
J	11.68	12.7				
K	12.7 —					
L	3.2 x 45° Typical					
All Dimensions in mm						

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	2KBP 005M	2KBP 01M	2KBP 02M	2KBP 04M	2KBP 06M	2KBP 08M	2KBP 10M	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @T _A = 50°C	lo	2.0					Α		
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	60						А	
Forward Voltage (per element) $@I_F = 2.0A$	VFM	и 1.1			V				
	lгм	10 500			μΑ				
Rating for Fusing (t<8.3ms)	l ² t	15					A ² s		
Typical Junction Capacitance per element (Note 2)	Cj	25					pF		
Typical Thermal Resistance (Note 3)	R_{θ} JA	30						K/W	
Operating and Storage Temperature Range	Тj, Тsтg	-55 to +165						°C	

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.

- 2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
- 3. Thermal resistance junction to ambient mounted on PC board with 12mm² copper pad.

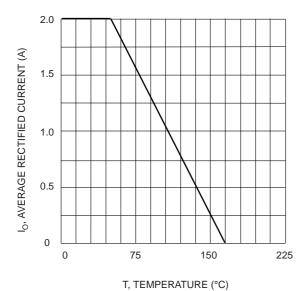


Fig. 1 Forward Current Derating Curve

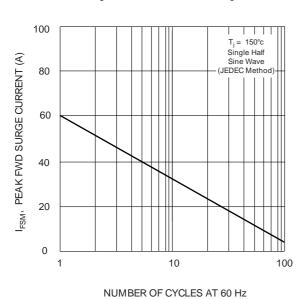
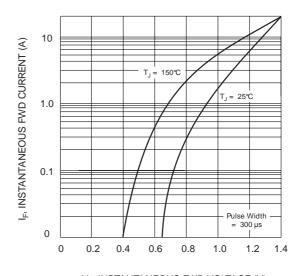
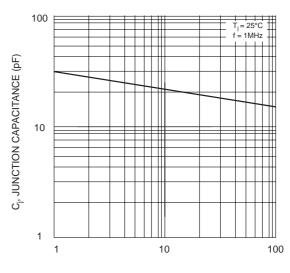


Fig. 3 Max Non-Repetitive Peak Fwd Surge Current



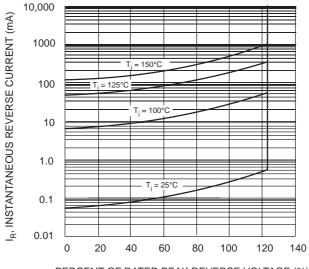
 $\mathrm{V_{F}},\,\mathrm{INSTANTANEOUS}\,\,\mathrm{FWD}\,\,\mathrm{VOLTAGE}\,\,\mathrm{(V)}$

Fig. 2 Typical Fwd Characteristics



V_R, REVERSE VOLTAGE (V)

Fig. 4 Typical Junction Capacitance



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

Fig. 5 Typical Reverse Characteristics

ORDERING INFORMATION

Product No.	Package Type	Shipping Quantity				
2KBP005M	SIL Bridge	1000 Units/Box				
2KBP01M	SIL Bridge	1000 Units/Box				
2KBP02M	SIL Bridge	1000 Units/Box				
2KBP04M	SIL Bridge	1000 Units/Box				
2KBP06M	SIL Bridge	1000 Units/Box				
2KBP08M	SIL Bridge	1000 Units/Box				
2KBP10M	SIL Bridge	1000 Units/Box				

Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.

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